



TDK FLASH STORAGE CATALOGUE

Nº
05



SMART INFRA: STORAGE

TDK-powered SSD solutions. Excelling anytime, anywhere, at any jobsite.

Manufacturing, transport, IT, financial, medical...

TDK flash storage devices help get the job right, in all domains.

On the land, across the seas, in the skies—24/7. SSD solutions from TDK, securing your jobsite again, today.

A large diamond-shaped collage composed of six smaller diamond-shaped images, each representing a different industry. The industries are labeled: MEDICAL (a woman in a white lab coat attending to a patient in a chair), FA (Factory Automation, showing a robotic arm on a production line), INFRASTRUCTURE (a modern train station with turnstiles), LIFE & ENTERTAINMENT (a hand holding a smartphone next to a keyboard), ICT (Information and Communications Technology, showing a server room), and ENERGY (a solar panel array with wind turbines in the background).

MEDICAL

FA

INFRASTRUCTURE

ENERGY

ICT

LIFE &
ENTERTAINMENT

SMART STORAGE, SMART FUTURE

TDK has developed the NAND-type flash memory controllers "GDriver" series realizing high speed access while securing data reliability. TDK has also developed Solid State Drives (SSDs) combining GDriver series inside, ideal solution for embedded systems.

CONTENTS

03 07 13

GDriver

Product Features

Product Lineup

GDriver

2003 2004 2005 2006 2007 2008 2009 2010 2011 2012 2014 2017 2018 2020

RA3



XR



RA4



RA6



RA7



RS1



RA8



RS2



RS3



RS4



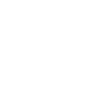
GS1



RA9



RD4



GS2



Flash Memory Controller IC GBDriver series

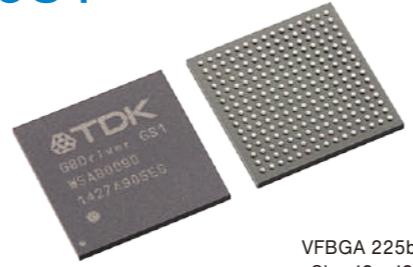
For 3D NAND

Product NAME	HOST INTERFACE	Operating Temperature
GS2  TFBGA 225ball (pitch 0.8mm) Size:13 x 13 x 1.2mm	SATA 1.5Gbps/3.0Gbps/6.0Gbps	-40 to +85°C

SSD controller for 3D NAND : GBDriver GS2

GBDriver GS2 is a highly reliable 3D flash memory controller IC with both hardware and firmware designed in-house (TDK) specifically for industrial use. As 3D flash memory technology advances, high-capacity flash storage solutions are more widely used and data reliability requirements are becoming increasingly sophisticated. Even in the industrial equipment sector, there is a growing need to improve performance while maintaining high data reliability. GBDriver GS2 not only adds new functions for 3D-NAND Flash memory but also uses TDK's proprietary technology to achieve high-speed access while enhancing power interruption tolerance and preventing data corruption.

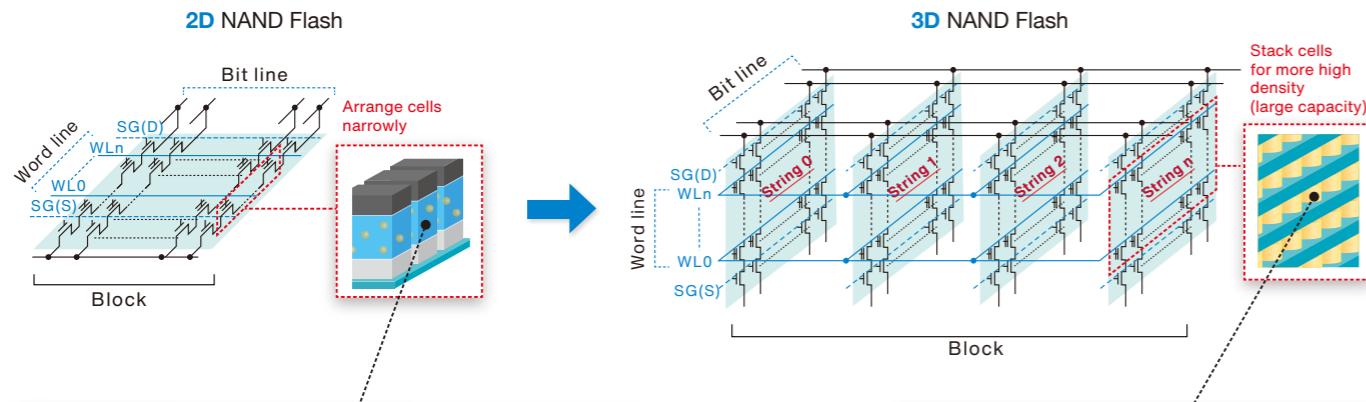
For 2D NAND

Product NAME	HOST INTERFACE	Operating Temperature
GS1  VFBGA 225ball (pitch 0.9mm) Size:13 x 13 x 1.2mm	SATA 1.5Gbps/3.0Gbps/6.0Gbps	-40 to +85°C
RS3  VFBGA 144ball (pitch 0.8mm) Size:12 x 12 x 1.4mm	SATA 1.5Gbps/3.0Gbps	-40 to +85°C

Product NAME	HOST INTERFACE					Operating Temperature
	PCMCIA ATA	Compact Flash	IDE	Direct Bus Connect	Inter-face	
RA9  TQFP 128pin (pitch 0.40mm) Size:16 x 16 x 1.2mm VFBGA 121ball (pitch 0.65mm) Size:8 x 8 x 0.99mm	○	4.1	PIO6 — MDMA4	— ○	133 MByte/sec	-40 to +85°C

2D NAND vs 3D NAND

NAND flash memory has changed from the 2D plane array cell structure to the 3D stacked cell structure. In 3D-NAND flash memory, the flash type can be selected from SLC mode and TLC.



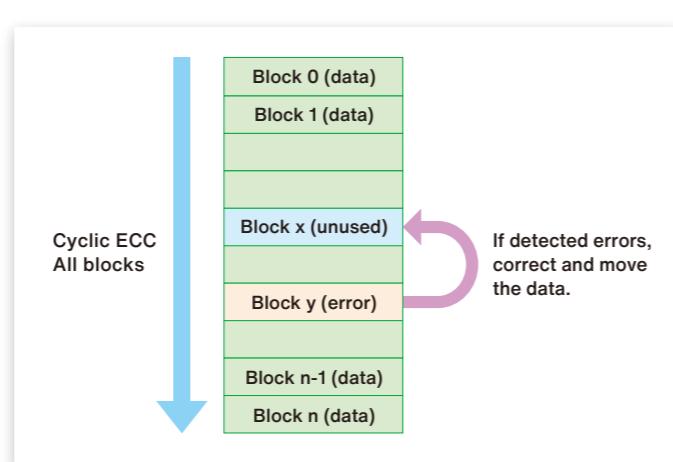
SLC	SLC mode	MLC
Endurance [P/E per Block]	100K/50K	20K
Data retention	10 years @ life begin – 10% 1year @ life end	01 00 10
	0	01 00 10
	1	11
1bit/cell(2state)	1bit/cell(2state)	2bit/cell(4state)

SLC mode	TLC
Endurance [P/E per Block]	30K
Data retention	10 years @ life begin 1year @ life end
	011 010 000 001 101 100 110
	0
1bit/cell(2state)	111
3bit/cell(8state)	1

Cyclic auto refresh function secures data retention.

TDK SSDs are equipped with a cyclic auto refresh function which automatically checks data and recovers errors by ECC. "Refresh" are executed at every boot and every 24hours.

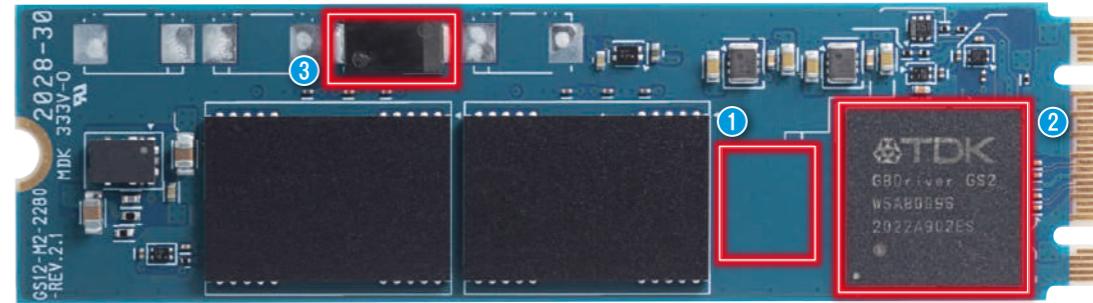
* This function works in background process when there is no access from host system.



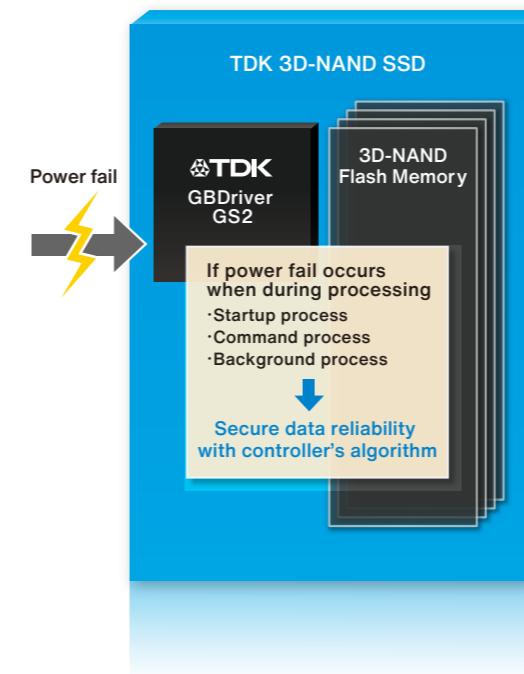
Countermeasures for power interruption

TDK's SSDs are designed with an emphasis on power interruption tolerance. The combination of the following three measures provides an overwhelming level of tolerance.

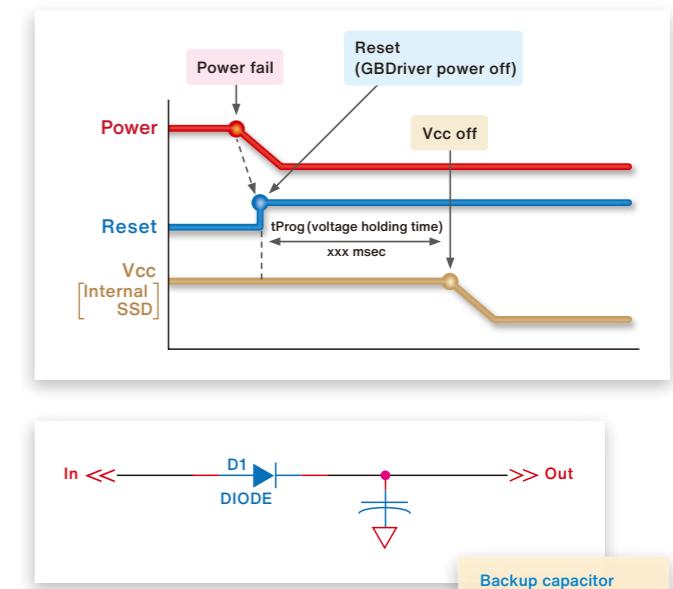
① DRAM-less design



② GBDriver GS2 algorithm (firmware)



③ Power backup circuit (on PCB)



TDK SSDs secure data reliability in sudden power fail.

① SSDs, Power shutdown test result

	TDK	A	B
Writing data sectors	2837558584	3966531026	2015419396
Power off cycles	677	946	481
Data errors	0 (0.00%)	859 (91%)	68 (14%)

② SD Memory cards, Power shutdown test result

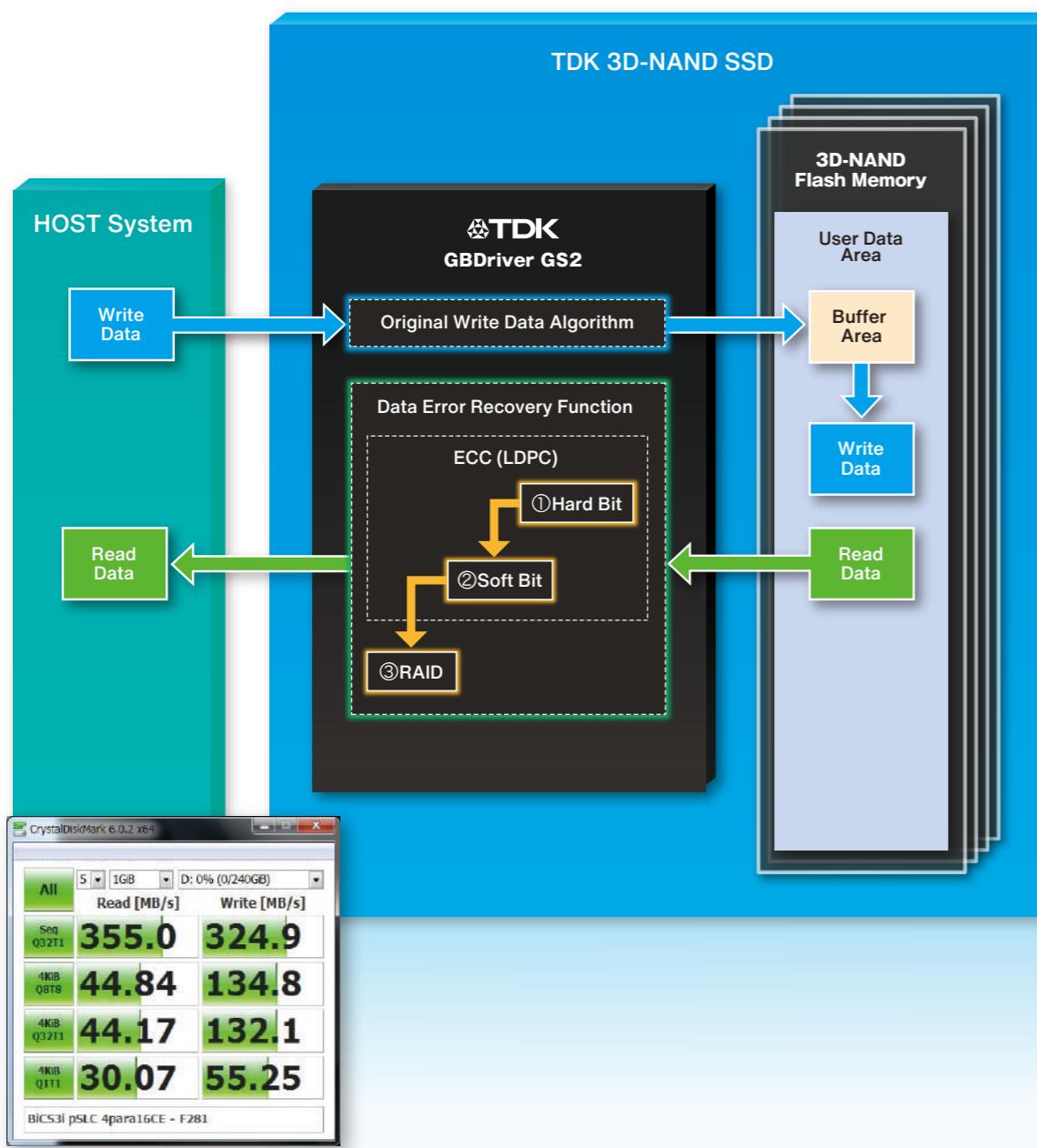
	TDK	A	B
Writing data sectors	166,049,542	27,296,954	5,791,942
Power off cycles	15,989	7,155	753
Data errors	0 (0.00%)	2 (0.03%)	1 (0.13%)

High-speed performance without the use of DRAM

TDK's 3D-SSD achieves high-speed performance despite its DRAM-less design in order to prioritize power failure tolerance (power interruption tolerance)

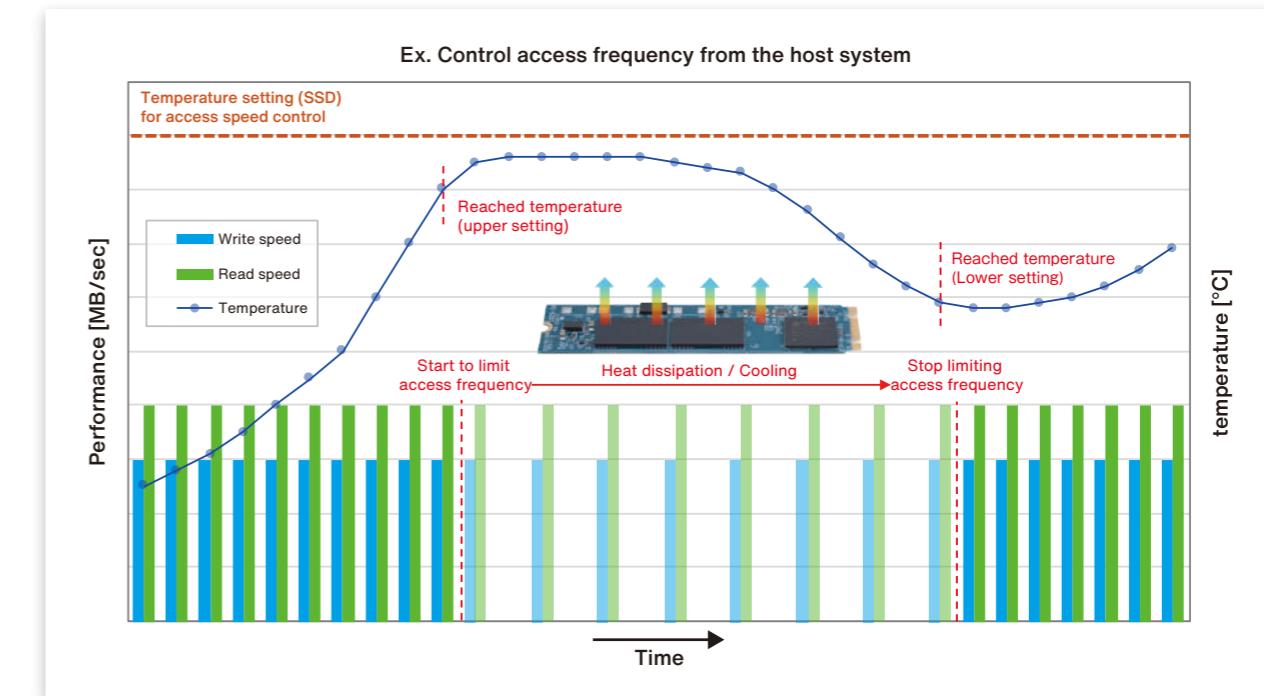
Data error recovery (LDPC/RAID)

TDK GBDriver GS2 has advanced data error recovery. When reading data from SSD, three functions work in stages. Depending on the data error situation, (1) LDPC Hard Bit, (2) LDPC Soft Bit, and (3) RAID are operated in this order as necessary to repair the error.



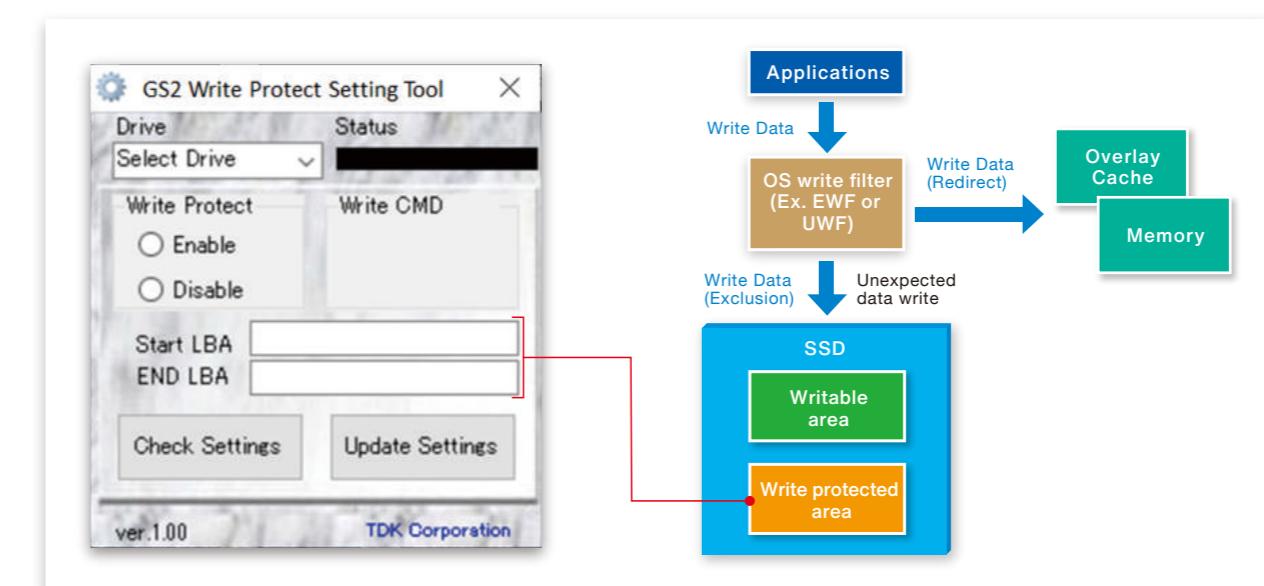
Temperature sensor and access speed limit

The on-board temperature sensor allows user to monitor the temperature of the SSD and limit access to the SSD from the host. The SSD also has a function to limit the access speed when the temperature setting value is exceeded.



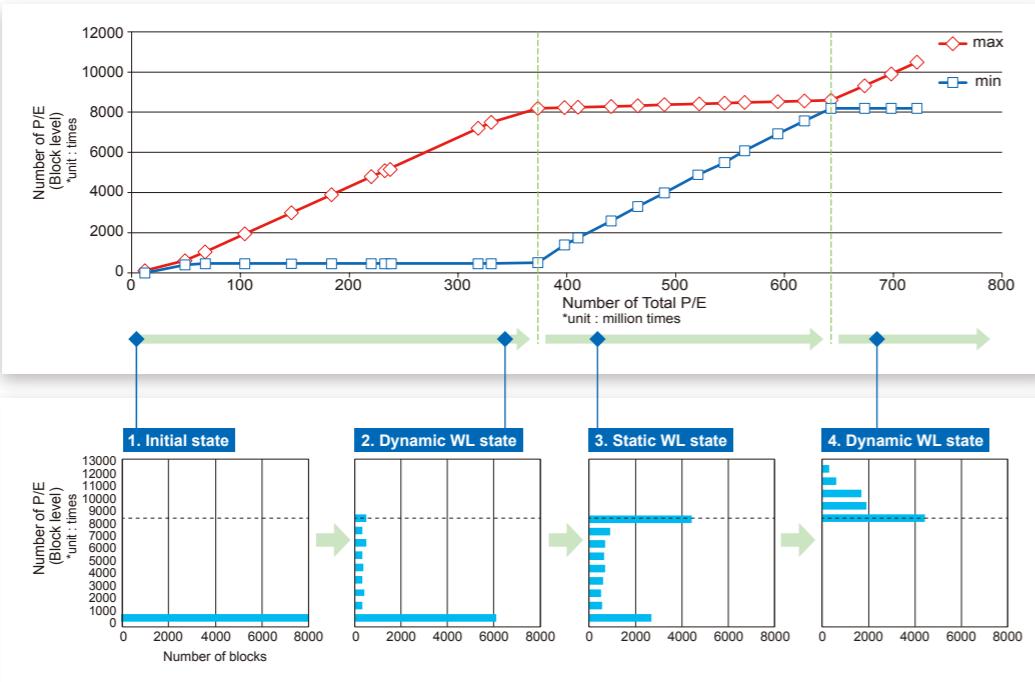
Write protected area setting function

TDK SSDs can be configured with a write-protected area, making it possible to reduce the need for power interruption (power failure) countermeasures on the host side.
(For example, to prevent writes that occur when using the Windows UWF function)
Our original software to configure this function is available upon request.

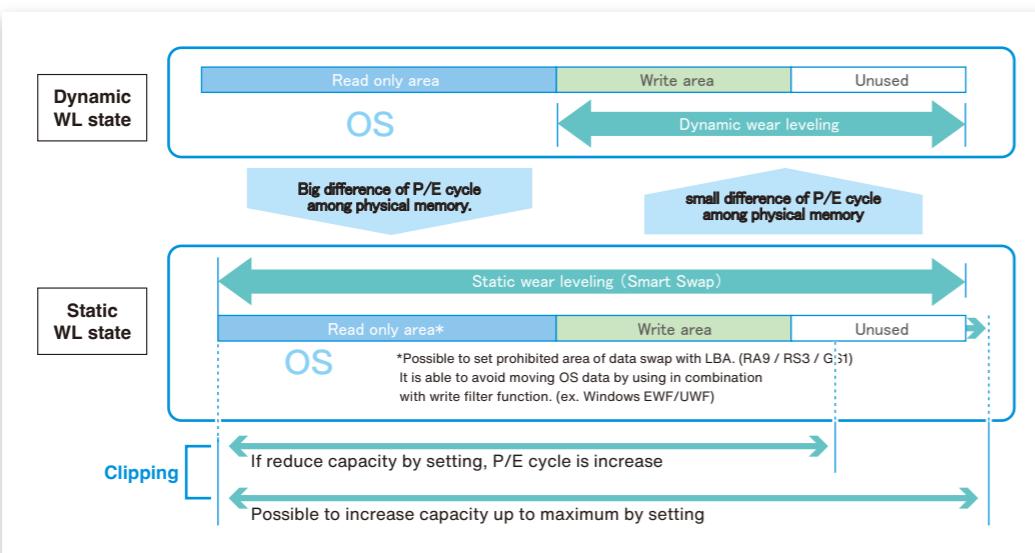


Longevity and ECO Friendly

In order to extend the longevity, our products execute "TDK global static wear leveling (TDK SMART SWAP)" and level P/E count of NAND flash cells(blocks) efficiently. Storage replacement is Low frequency and it is Lower TCO (Total Cost of Ownership).



TDK global static wear leveling (TDK SMART SWAP)



Clipping (Number of sector setting)

Possible to adjust number of sector for user data area in unit of a sector.

TDK SMART (Flash storage life monitor – Endurance analysis program)

TDK SMART provides various information(following) and could predict storages life.

- Number of flash memory chips, number of blocks
- Number of total P/E cycles, Number of highest/lowest P/E cycles among blocks
- Total P/E cycles for all blocks(in a 10-level histogram)
- Memory usage[%], Life indicator[%]

Tools for Windows OS are Available for download on TDK web site. <https://product.tdk.com/info/en/products/flash-storage/flash-storage/tdksmart.html>
*Please contact us if you need to receive detailed information. (addresses of various parameters, command operation, etc..)



Product Lineup

[3D NAND Storage]

CFast™

CAT2A



GENERAL INFORMATION

TYPE	CFast™			
INTERFACE	Serial ATA Revision 3.1			
DATA TRANSFER MODE	SATA 1.5Gbps, 3.0Gbps, 6.0Gbps			
CONNECTOR	CFast™ Type I			
OUTLINE DIMENSIONS	36.4 x 42.8 x 3.6 mm			
SERIES	CAT2A			
CONTROLLER TYPE	TDK GBDriver GS2			
FLASH TYPE	3D-pSLC (SLC mode)	3D - Gen3	3D - Gen5	3D-TLC (TLC mode)
	3D - Gen3	3D - Gen5	3D - Gen3	3D - Gen5
DENSITY RANGE	16 GB - 128 GB	16 GB - 256 GB	50 GB - 400 GB	50 GB - 800 GB
DATA RETENTION	10 years @ life begin 1 year @ life end			
ENDURANCE	30,000 P/E Cycles	3,000 P/E Cycles		
ENTERPRISE WL	*Flash Block Level	*Flash Block Level		

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C

PERFORMANCE

Read (max.)	345 MByte/sec
Write (max.)	295 MByte/sec

ROBUSTNESS

MTBF	≥ 2,000,000 hours
SHOCK	1500G, 0.5ms
VIBRATION	20G, 10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	3.3 V ± 5 %
POWER CONSUMPTION (*RT)	- Read: 1140 mW max. - Write: 1370 mW max. - Slumber: 200mW

FEATURE LIST

FEATURES & TOOLS	<ul style="list-style-type: none"> - In-House Designed Controller (HW/FW) - SLC Cache, LDPC-ECC, RAID - Temperature monitoring function - Write-protected area setting tool (on request) - DRAM-less Design - Power Fail Data Safety - Power Back-up Circuit - Global static wear leveling - SMART (life monitor) - NCQ, TRIM - AES 256 bit encryption, TCG-OPAL (on request)
PART NUMBER	CAT2AxxxxKHxxA00EAA0 CAT2AxxxxKMxxA00EAA0 CAT2AxxxxKGxxA00EAA0 CAT2AxxxxKLxxA00EAA0

[2D NAND Storage]

CFast™

CAE3B



CAE1B



GENERAL INFORMATION

TYPE	CFast™			
INTERFACE	Serial ATA Revision 2.6			
DATA TRANSFER MODE	SATA 1.5Gbps, 3.0Gbps			
CONNECTOR	CFast™ Type I			
OUTLINE DIMENSIONS	36.4 x 42.8 x 3.6 mm			
SERIES	CAE3B	CAE1B		
CONTROLLER TYPE	TDK GBDriver RS3	TDK GBDriver GS1		
FLASH TYPE	SLC	SLC	pSLC	MLC
DENSITY RANGE	512 MB - 8 GB	16 GB - 64 GB	16 GB - 128 GB	32 GB - 256 GB
DATA RETENTION	10 years @ life begin-10% 1 year @ life end			
ENDURANCE	50,000 P/E Cycles	100,000 P/E Cycles	20,000 P/E Cycles	3,000 P/E Cycles
ENTERPRISE WL	*Flash Block Level	*Flash Block Level	*Flash Block Level	*Flash Block Level

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C

PERFORMANCE

Read (max.)	105 MByte/sec	340 MByte/sec	345 MByte/sec	295 MByte/sec
Write (max.)	60 MByte/sec	105 MByte/sec	145 MByte/sec	75 MByte/sec

ROBUSTNESS

MTBF	≥ 2,000,000 hours
SHOCK	1500G, 0.5ms
VIBRATION	20G, 10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	3.3 V ± 5 %
POWER CONSUMPTION (*RT)	<ul style="list-style-type: none"> - Read Write: 125 / 215 / 365mA max. (Single / 2ch / 4ch) - Slumber: less than 50mA

FEATURE LIST

FEATURES & TOOLS	<ul style="list-style-type: none"> - In-House Designed Controller - DRAM-less Design - Power Fail Data Safety - Global static wear leveling - SMART - NCQ, TRIM - AES 128bit encryption (on request) 	<ul style="list-style-type: none"> - In-House Designed Controller - DRAM-less Design - Power Fail Data Safety - Global static wear leveling - SMART - NCQ, TRIM - AES 128/256bit encryption (on request)
PART NUMBER	CAE3BxxxxTxxxB00EAA0	CAE1BxxxxTXDxB00EAA0 CAE1BxxxxTKDxB00EAA0 CAE1BxxxxTFDxB00EAA0

Product Lineup

[3D NAND Storage]

2.5" SATA SSD

FC CE UK
CA

SDT2A



GENERAL INFORMATION

TYPE	2.5 inch SATA SSD (7mm / 9mm)			
INTERFACE	Serial ATA Revision 3.1			
DATA TRANSFER MODE	SATA 1.5Gbps, 3.0Gbps, 6.0Gbps			
CONNECTOR	15 + 7 pin Serial ATA			
OUTLINE DIMENSIONS	100.2 x 69.85 x 7 mm / 9.5 mm			
SERIES	SDT2A			
CONTROLLER TYPE	 TDK GBDriver GS2			
FLASH TYPE	3D-pSLC (SLC mode)	3D - Gen3	3D - Gen5	3D-TLC (TLC mode)
DENSITY RANGE	16 GB - 256GB	16 GB - 512 GB	50 GB - 800 GB	50 GB - 1600 GB
DATA RETENTION	10 years @ life begin 1 year @ life end			
ENDURANCE	30,000 P/E Cycles	3,000 P/E Cycles		
ENTERPRISE WL	*Flash Block Level	*Flash Block Level		

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C

PERFORMANCE

Read (max.)	345 MByte/sec
Write (max.)	295 MByte/sec

ROBUSTNESS

MTBF	≥ 2,000,000 hours
SHOCK	1,000G,1.0ms
VIBRATION	20G,10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	5 V ± 10 %
POWER CONSUMPTION (*RT)	- Read: 1070 mW max. - Write: 1270 mW max. - Slumber: 200mW

FEATURE LIST

FEATURES & TOOLS	<ul style="list-style-type: none"> - In-House Designed Controller (HW/FW) - SLC Cache, LDPC-ECC, RAID - Temperature monitoring function - Write-protected area setting tool (on request) - DRAM-less Design - Power Fail Data Safety - Power Back-up Circuit - Global static wear leveling - SMART (life monitor) - NCQ, TRIM - AES 256 bit encryption, TCG-OPAL (on request)
PART NUMBER	SDT2AxxxxKHxxAx0ESA0 SDT2AxxxxKMxxAx0ESA0 SDT2AxxxxKGxxAx0ESA0 SDT2AxxxxKLxxAx0ESA0

[2D NAND Storage]

2.5" SATA SSD

FC CE UK
CA

SDE1B



GENERAL INFORMATION

TYPE	2.5 inch SATA SSD (7mm / 9mm)		
INTERFACE	Serial ATA Revision 3.1		
DATA TRANSFER MODE	SATA 1.5Gbps, 3.0Gbps, 6.0Gbps		
CONNECTOR	15 + 7 pin Serial ATA		
OUTLINE DIMENSIONS	100.2 x 69.85 x 7 mm / 9.5 mm		
SERIES	SDE1B		
CONTROLLER TYPE	 TDK GBDriver GS1		
FLASH TYPE	SLC	pSLC	MLC
DENSITY RANGE	16 GB - 128 GB	16 GB - 256 GB	32 GB - 512 GB
DATA RETENTION	10 years @ life begin-10% 1 year @ life end		
ENDURANCE	100,000 P/E Cycles	20,000 P/E Cycles	3,000 P/E Cycles
ENTERPRISE WL	*Flash Block Level	*Flash Block Level	*Flash Block Level

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C

PERFORMANCE

Read (max.)	420 MByte/sec
Write (max.)	305 MByte/sec

ROBUSTNESS

MTBF	≥ 2,000,000 hours
SHOCK	1,000G,1.0ms
VIBRATION	20G,10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	5 V ± 10 %
POWER CONSUMPTION (*RT)	<ul style="list-style-type: none"> - Read: 320mA max. - Write: 600mA max. - Slumber: less than 100mA

FEATURE LIST

FEATURES & TOOLS	<ul style="list-style-type: none"> - In-House Designed Controller - DRAM-less Design - Power Fail Data Safety - Power Back-up Circuit - Global static wear leveling - SMART - NCQ, TRIM - AES 128/256bit encryption (on request)
PART NUMBER	SDE1BxxxxTXxBx0ESA0 SDE1BxxxxTKxxBx0ESA0 SDE1BxxxxTFxxBx0ESA0

Product Lineup

[3D NAND Storage]

Half Slim

FC CE UK
CA

SHT2A



GENERAL INFORMATION

TYPE	Half Slim			
INTERFACE	Serial ATA Revision 3.1			
DATA TRANSFER MODE	SATA 1.5Gbps, 3.0Gbps, 6.0Gbps			
CONNECTOR	15 + 7 pin Serial ATA			
OUTLINE DIMENSIONS	54 x 39 mm			
SERIES	SHT2A			
CONTROLLER TYPE	TDK GBDriver GS2			
FLASH TYPE	3D-pSLC (SLC mode)	3D - Gen3	3D-TLC (TLC mode)	3D - Gen5
DENSITY RANGE	8 GB - 256GB	16 GB - 512 GB	25 GB - 800 GB	50 GB - 1600 GB
DATA RETENTION	10 years @ life begin 1 year @ life end			
ENDURANCE	30,000 P/E Cycles		3,000 P/E Cycles	
ENTERPRISE WL	*Flash Block Level		*Flash Block Level	

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C

PERFORMANCE

Read (max.)	345 MByte/sec
Write (max.)	295 MByte/sec

ROBUSTNESS

MTBF	≥ 2,000,000 hours
SHOCK	1500G, 0.5ms
VIBRATION	20G, 10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	5 V ± 10 %
POWER CONSUMPTION (*RT)	- Read: 1070 mW max. - Write: 1270 mW max. - Slumber: 200mW

FEATURE LIST

FEATURES & TOOLS	<ul style="list-style-type: none"> - In-House Designed Controller (HW/FW) - SLC Cache, LDPC-ECC, RAID - Temperature monitoring function - Write-protected area setting tool (on request) - DRAM-less Design - Power Fail Data Safety - Power Back-up Circuit - Global static wear leveling - SMART (life monitor) - NCQ, TRIM - AES 256 bit encryption, TCG-OPAL (on request)
PART NUMBER	SHT2AxxxxKxxxA00ESA0 SHT2AxxxxKMxxA00ESA0 SHT2AxxxxKxxxA00ESA0 SHT2AxxxxKLxxA00ESA0

[2D NAND Storage]

Half Slim

FC CE UK
CA

SHE1B



GENERAL INFORMATION

TYPE	Half Slim		
INTERFACE	Serial ATA Revision 3.1		
DATA TRANSFER MODE	SATA 1.5Gbps, 3.0Gbps, 6.0Gbps		
CONNECTOR	15 + 7 pin Serial ATA		
OUTLINE DIMENSIONS	54 x 39 mm		
SERIES	SHE1B		
CONTROLLER TYPE	TDK GBDriver GS1		
FLASH TYPE	SLC	pSLC	MLC
DENSITY RANGE	16 GB - 128 GB	16 GB - 256 GB	32 GB - 512 GB
DATA RETENTION	10 years @ life begin-10% 1 year @ life end		
ENDURANCE	100,000 P/E Cycles	20,000 P/E Cycles	3,000 P/E Cycles
ENTERPRISE WL	*Flash Block Level	*Flash Block Level	*Flash Block Level

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C

PERFORMANCE

Read (max.)	340 MByte/sec
Write (max.)	115 MByte/sec

ROBUSTNESS

MTBF	≥ 2,000,000 hours
SHOCK	1500G, 0.5ms
VIBRATION	20G, 10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	5 V ± 10 %
POWER CONSUMPTION (*RT)	- Read: 250mA max. - Write: 270mA max. - Slumber: less than 100mA

FEATURE LIST

FEATURES & TOOLS	<ul style="list-style-type: none"> - In-House Designed Controller - DRAM-less Design - Power Fail Data Safety - Power Back-up Circuit - Global static wear leveling - SMART - NCQ, TRIM - AES 128/256bit encryption (on request)
PART NUMBER	SHE1BxxxxTXDxB00SSA0 SHE1BxxxxTKDxB00SSA0 SHE1BxxxxTFDxB00SSA0

Product Lineup

[3D NAND Storage]

mSATA



SMT2A



GENERAL INFORMATION

TYPE	mSATA			
INTERFACE	Serial ATA Revision 3.1			
DATA TRANSFER MODE	SATA 1.5Gbps, 3.0Gbps, 6.0Gbps			
CONNECTOR	52 pin. Edge			
OUTLINE DIMENSIONS	50.8 x 29.85 mm			
SERIES	SMT2A			
CONTROLLER TYPE	TDK GBDriver GS2			
FLASH TYPE	3D-pSLC (SLC mode)	3D - Gen3	3D-TLC (TLC mode)	3D - Gen5
3D - Gen3	3D - Gen5	3D - Gen3	3D - Gen5	
DENSITY RANGE	16 GB - 128 GB	16 GB - 256 GB	50 GB - 400 GB	50 GB - 800 GB
DATA RETENTION	10 years @ life begin 1 year @ life end			
ENDURANCE	30,000 P/E Cycles		3,000 P/E Cycles	
ENTERPRISE WL	*Flash Block Level		*Flash Block Level	

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C

PERFORMANCE

Read (max.)	345 MByte/sec
Write (max.)	295 MByte/sec

ROBUSTNESS

MTBF	≥ 2,000,000 hours
SHOCK	1500G, 0.5ms
VIBRATION	20G, 10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	3.3 V ± 5 %
POWER CONSUMPTION (*RT)	- Read: 1140 mW max. - Write: 1370 mW max. - Slumber: 200mW

FEATURE LIST

FEATURES & TOOLS	<ul style="list-style-type: none"> - In-House Designed Controller (HW/FW) - SLC Cache, LDPC-ECC, RAID - Temperature monitoring function - Write-protected area setting tool (on request) - DRAM-less Design - Power Fail Data Safety - Power Back-up Circuit - Global static wear leveling - SMART (life monitor) - NCQ, TRIM - AES 256 bit encryption, TCG-OPAL (on request)
PART NUMBER	SMT2AxxxxKHxxA00ESA0 SMT2AxxxxKMxxA00ESA0 SMT2AxxxxKGxxA00ESA0 SMT2AxxxxKLxxA00ESA0

[2D NAND Storage]

mSATA



SME3B



SME1B



GENERAL INFORMATION

TYPE	mSATA					
INTERFACE	Serial ATA Revision 2.6	Serial ATA Revision 3.1				
DATA TRANSFER MODE	SATA 1.5Gbps, 3.0Gbps	SATA 1.5Gbps, 3.0Gbps, 6.0Gbps				
CONNECTOR	52 pin. Edge					
OUTLINE DIMENSIONS	50.8 x 29.85 mm					
SERIES	SME3B	SME1B				
CONTROLLER TYPE	TDK GBDriver RS3	TDK GBDriver GS1				
FLASH TYPE	SLC	SLC	pSLC	MLC		
DENSITY RANGE	512 MB - 8 GB	16 GB - 64 GB	16 GB - 128 GB	32 GB - 256 GB		
DATA RETENTION	10 years @ life begin-10% 1 year @ life end					
ENDURANCE	50,000 P/E Cycles	100,000 P/E Cycles	20,000 P/E Cycles	3,000 P/E Cycles		
ENTERPRISE WL	*Flash Block Level	*Flash Block Level	*Flash Block Level	*Flash Block Level		

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C

PERFORMANCE

Read (max.)	160 MByte/sec	340 MByte/sec	345 MByte/sec	295 MByte/sec
Write (max.)	80 MByte/sec	105 MByte/sec	145 MByte/sec	75 MByte/sec

ROBUSTNESS

MTBF	≥ 2,000,000 hours
SHOCK	1500G, 0.5ms
VIBRATION	20G, 10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	3.3 V ± 5 %
POWER CONSUMPTION (*RT)	<ul style="list-style-type: none"> - Read Write: 160 / 275 / 470mA max. (Single / 2ch / 4ch) - Slumber: less than 50mA

FEATURE LIST

FEATURES & TOOLS	<ul style="list-style-type: none"> - In-House Designed Controller - DRAM-less Design - Power Fail Data Safety - Global static wear leveling - SMART - NCQ, TRIM - AES 128bit encryption (on request) 	<ul style="list-style-type: none"> - In-House Designed Controller - DRAM-less Design - Power Fail Data Safety - Global static wear leveling - SMART - NCQ, TRIM - AES 128/256bit encryption (on request)
PART NUMBER	SME3BxxxxTxxxB00SSA0	SME1BxxxxTKDxB00SSA0 SME1BxxxxTFDxB00SSA0

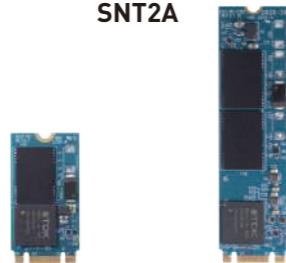
Product Lineup

[3D NAND Storage]

M.2



SNT2A



GENERAL INFORMATION

TYPE	M.2 (2242 / 2280)			
INTERFACE	Serial ATA Revision 3.1			
DATA TRANSFER MODE	SATA 1.5Gbps, 3.0Gbps, 6.0Gbps			
CONNECTOR	75 pin. Edge B & M key			
OUTLINE DIMENSIONS	22 x 42 mm / 80mm			
SERIES	SNT2A			
CONTROLLER TYPE	TDK GBDriver GS2			
FLASH TYPE	3D-pSLC (SLC mode)	3D - Gen3	3D - Gen5	3D-TLC (TLC mode)
DENSITY RANGE	2242 : 16 GB - 128 GB 2280 : 16 GB - 256 GB	2242 : 16 GB - 256 GB 2280 : 16 GB - 512 GB	2242 : 50 GB - 400 GB 2280 : 50 GB - 800 GB	2242 : 50 GB - 800 GB 2280 : 50 GB - 1600 GB
DATA RETENTION	10 years @ life begin 1 year @ life end			
ENDURANCE	30,000 P/E Cycles	3,000 P/E Cycles		
ENTERPRISE WL	*Flash Block Level	*Flash Block Level		

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C

PERFORMANCE

Read (max.)	345 MByte/sec
Write (max.)	295 MByte/sec

ROBUSTNESS

MTBF	≥ 2,500,000 hours
SHOCK	1500G,0.5ms
VIBRATION	20G,10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	3.3 V ± 5 %
POWER CONSUMPTION (*RT)	- Read: 1140 mW max. - Write: 1370 mW max. - Slumber: 200mW

FEATURE LIST

FEATURES & TOOLS	<ul style="list-style-type: none"> - In-House Designed Controller (HW/FW) <ul style="list-style-type: none"> - SLC Cache, LDPC-ECC, RAID - Temperature monitoring function - Write-protected area setting tool (on request) <ul style="list-style-type: none"> - DRAM-less Design - Power Fail Data Safety - Power Back-up Circuit - Global static wear leveling - SMART (life monitor) - NCQ, TRIM - AES 256 bit encryption, TCG-OPAL (on request)
PART NUMBER	SNT2AxxxxKHxxAx0ESA0 SNT2AxxxxKMxxAx0ESA0 SNT2AxxxxKGxxAx0ESA0 SNT2AxxxxKLxxAx0ESA0

[2D NAND Storage]

M.2



SNE1B



GENERAL INFORMATION

TYPE	M.2 (2242 / 2280)		
INTERFACE	Serial ATA Revision 3.1		
DATA TRANSFER MODE	SATA 1.5Gbps, 3.0Gbps, 6.0Gbps		
CONNECTOR	75 pin. Edge B & M key		
OUTLINE DIMENSIONS	22 x 42 mm / 80mm		
SERIES	SNE1B		
CONTROLLER TYPE	TDK GBDriver GS1		
FLASH TYPE	SLC	pSLC	MLC
DENSITY RANGE	2242 : 16 GB - 64 GB 2280 : 16GB - 128GB	2242 : 16 GB - 128 GB 2280 : 16 GB - 256 GB	2242 : 32 GB - 256 GB 2280 : 32 GB - 512 GB
DATA RETENTION	10 years @ life begin-10% 1 year @ life end		
ENDURANCE	100,000 P/E Cycles	20,000 P/E Cycles	3,000 P/E Cycles
ENTERPRISE WL	*Flash Block Level	*Flash Block Level	*Flash Block Level

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C

PERFORMANCE

Read (max.)	340 MByte/sec
Write (max.)	105 MByte/sec

ROBUSTNESS

MTBF	≥ 2,500,000 hours
SHOCK	1500G,0.5ms
VIBRATION	20G,10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	3.3 V ± 5 %
POWER CONSUMPTION (*RT)	- Read: 385mA max. - Write: 370mA max. - Slumber: less than 100mA

FEATURE LIST

FEATURES & TOOLS	<ul style="list-style-type: none"> - In-House Designed Controller - DRAM-less Design - Power Fail Data Safety - Power Back-up Circuit - Global static wear leveling - SMART - NCQ, TRIM - AES 128/256bit encryption (on request)
PART NUMBER	SNE1BxxxxTxDxBx0SSA0 SNE1BxxxxTKDxBx0SSA0 SNE1BxxxxTFDxBx0SSA0

Product Lineup

[2D NAND Storage]

Compact Flash™ / 2.5" PATA SSD

CFE9D



CE UK
CA

SDE9D



GENERAL INFORMATION

TYPE	CompactFlash™	2.5 inch PATA SSD
INTERFACE	PCMCIA/IDE	IDE
DATA TRANSFER MODE	UDMA0-6, MDMA0-4 & PIO0-6	UDMA0-6, MDMA0-4 & PIO0-6
CONNECTOR	CFC Type I	44PIN
OUTLINE DIMENSIONS	36.4 x 42.8 x 3.3 mm	100 x 69.85 x 9.5 mm
SERIES	CFE9D	SDE9D
CONTROLLER TYPE	TDK GBDriver RA9	
FLASH TYPE	SLC	SLC
DENSITY RANGE	128 MB - 32 GB	1 GB - 64 GB
DATA RETENTION	10 years @ life begin-10% 1 year @ life end	
ENDURANCE	128 MB ~ 4 GB:50,000 P/E Cycles	1 GB ~ 4 GB:50,000 P/E Cycles
ENTERPRISE WL	8 GB ~ 32 GB:100,000 P/E Cycles *Flash Block Level	8 GB ~ 32 GB:100,000 P/E Cycles *Flash Block Level

TEMPERATURE

OPERATING TEMPERATURE	Commercial:0°C to +70°C Industrial:-40°C to +85°C
STORAGE TEMPERATURE	Commercial:-25°C to +85°C Industrial:-40°C to +85°C

PERFORMANCE

Read (max.)	50 MByte/sec
Write (max.)	35 MByte/sec

ROBUSTNESS

MTBF	≥ 2,500,000 hours	≥ 2,000,000 hours
SHOCK	1000G,0.5ms	1500G,1.0ms
VIBRATION	15G,10-500Hz	20G,10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)	

ELECTRICAL DATA

VOLTAGE	3.3 V ± 5 % / 5 V ± 10 %	5 V ± 10 %
POWER CONSUMPTION (*RT)	- Single mode UDMA Read Write: 145mA @ 3.3V / 85mA @ 5.0V - 2ch mode UDMA Read Write: 220mA @ 3.3V / 130mA @ 5.0V - Stand-by:10mA @ 3.3V / 10mA @ 5.0V	- Single mode UDMA Read Write:80mA - 2ch mode UDMA Read Write:135mA - Stand-by:5mA

FEATURE LIST

FEATURES & TOOLS	- In-House Designed Controller (HW/FW) - DRAM-less Design - Power Fail Data Safety - Power Back-up Circuit - Global static wear leveling - SMART - TRIM	- In-House Designed Controller (HW/FW) - DRAM-less Design - Power Fail Data Safety - Power Back-up Circuit - Global static wear leveling - SMART - TRIM
PART NUMBER	CFE9DxxxxTxxxB00EAA0	SDE9DxxxxTxxxB00ESA0

[2D NAND Storage]

SD Card / Micro SD Card

MMRD4



MURD4



CE UK
CA

GENERAL INFORMATION

TYPE	SD MEMORY CARD (SD / SDHC)	microSD MEMORY CARD (SD / SDHC)
INTERFACE	SD 3.0, UHS-I/Class 10 (SDHC) , Class 6 (SD)	
DATA TRANSFER MODE		
CONNECTOR	SD	microSD
OUTLINE DIMENSIONS	32 x 24 x 2.1 mm	15 x 11 x 0.7 / 1 mm
SERIES	MMRD4	MURD4
CONTROLLER TYPE	TDK GBDriver RD4	
FLASH TYPE	SLC	pSLC
DENSITY RANGE	512 MB - 32 GB	1 GB - 32 GB
DATA RETENTION	10 years @ life begin-10% 1 year @ life end	
ENDURANCE	512 MB ~ 2 GB: 50,000 P/E Cycles	20,000 P/E Cycles
ENTERPRISE WL	4 GB ~ 32 GB: 100,000 P/E Cycles *Flash Block Level	*Flash Block Level

TEMPERATURE

OPERATING TEMPERATURE	Commercial: -25°C to +85°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	-40°C to +85°C

PERFORMANCE

Read (max.)	75 MByte/sec	64 MByte/sec	75 MByte/sec	64 MByte/sec
Write (max.)	50 MByte/sec	67 MByte/sec	50 MByte/sec	67 MByte/sec

ROBUSTNESS

MTBF	≥ 3,000,000 hours
SHOCK	1000G,0.5ms
VIBRATION	15G,10-2000Hz
HUMIDITY	0 to 90 % RH (No condensation)

ELECTRICAL DATA

VOLTAGE	2.7 ~ 3.6 V
POWER CONSUMPTION (*RT)	- Read: 100mA max. - Write: 100mA max. - Stand-by: 0.4mA

FEATURE LIST

FEATURES & TOOLS	- In-House Designed Controller - DRAM-less Design - Power Fail Data Safety - Global static wear leveling - SMART	
PART NUMBER	MMRD4xxxxVxxxA00ABA0	MURD4xxxxVxxxA00ABA0

Part Number

[3D NAND Storage]

	SLC mode Gen3	CAT2A016GKHBCA00EAA0 CAT2A032GKHDC00EAA0 CAT2A064GKHDC00EAA0 CAT2A128GKHDC00EAA0
	SLC Mode Gen5	CAT2A016GKMAC00EAA0 CAT2A032GKMBC00EAA0 CAT2A064GKMDCA00EAA0 CAT2A128GKMDCA00EAA0 CAT2A256GKMDCA00EAA0
	TLC mode Gen3	CAT2A050GKGBCA00EAA0 CAT2A100GKGDC00EAA0 CAT2A200GKGDC00EAA0 CAT2A400GKGDC00EAA0
	TLC Mode Gen5	CAT2A050GKLAC00EAA0 CAT2A100GKLBC00EAA0 CAT2A200GKLDCA00EAA0 CAT2A400GKLDCA00EAA0 CAT2A800GKLDCA00EAA0
		1) C:0~70°C>> W:-40~85°C
	SLC mode Gen3	SDT2A016GKHBCA00EAA0 SDT2A032GKHDC00EAA0 SDT2A064GKHDC00EAA0 SDT2A128GKHDC00EAA0 SDT2A256GKHDC00EAA0
	SLC Mode Gen5	SDT2A016GKMAC00EAA0 SDT2A032GKMBC00EAA0 SDT2A064GKMDCA00EAA0 SDT2A128GKMDCA00EAA0 SDT2A256GKMDCA00EAA0 SDT2A512GKMDCA00EAA0
	TLC mode Gen3	SDT2A050GKGBCA00EAA0 SDT2A100GKGDC00EAA0 SDT2A200GKGDC00EAA0 SDT2A400GKGDC00EAA0 SDT2A800GKGDC00EAA0
	TLC Mode Gen5	SDT2A050GKLAC00EAA0 SDT2A100GKLBC00EAA0 SDT2A200GKLDCA00EAA0 SDT2A400GKLDCA00EAA0 SDT2A800GKLDCA00EAA0
		1) C:0~70°C>> W:-40~85°C
		2) A:Case7mm>> O:Case9.5mm

◆Regarding this Document
Copyright and any other right with respect to the documents is solely owned by us. This document and any information herein may not be reproduced, modified, revised without prior written permission from us. All information included in this document is current as of date this document is issued and we reserve the right to make changes to the information in this document without notice. This document is presented only as reference for your evaluation of the products.
This document is prepared and provided "As Is" without warranty of any kind, either express or implied, including but not limited to, the accuracy or completeness of information included in this document, non-infringement of any third party's right of any kind, and implied warranties of satisfactory quality, fitness for a particular purpose. It is sole responsibility of you to determine the products are suitable and fit for your applications and products planned, as well as for the planned application and use of your customer(s).
Please confirm the latest specification sheet of the product with our sales office. Unless otherwise agreed, we do not make any warranty that the products conform to the specification other than those explicitly described in such latest specification sheet.

◆Restriction of liability
Except as provided in the relevant terms and conditions of sale for product, and to the maximum extent allowable by law, we assume no liability whatsoever, including without limitation, indirect, consequential, special, or incidental damages or loss, including without limitation, loss of profits, loss of opportunities, business interruption and loss of data.

◆Product inquiry
If you have any questions about this product, please feel free to contact TDK sales representative.

[2D NAND Storage]

	SLC	CAE3B512MTNACB00EAA0 CAE3B001GTNACB00EAA0 CAE3B002GTNACB00EAA0 CAE3B004GTNACB00EAA0 CAE3B008GTNDCB00EAA0
		1) C:0~70°C>> W:-40~85°C
	SLC	CAE1B016GTXDCB00SSA0 SHE1B032GTXDCB00SSA0 SHE1B064GTXDCB00SSA0 SHE1B128GTXDCB00SSA0
	SLC	CAE1B016GTXDCB00SSA0 SHE1B032GTXDCB00SSA0 SHE1B064GTXDCB00SSA0 SHE1B128GTXDCB00SSA0
	SLC	CAE1B016GTXDCB00SSA0 SHE1B032GTXDCB00SSA0 SHE1B064GTXDCB00SSA0 SHE1B128GTXDCB00SSA0
	SLC	CAE1B016GTXDCB00SSA0 SHE1B032GTXDCB00SSA0 SHE1B064GTXDCB00SSA0 SHE1B128GTXDCB00SSA0
	MLC	CAE1B032GTFDCB00SSA0 SHE1B064GTFDCB00SSA0 SHE1B128GTFDCB00SSA0 SHE1B256GTFDCB00SSA0
		1) C:0~70°C>> W:-40~85°C
	SLC	SME3B512MTNACB00SSA0 SME3B001GTNACB00SSA0 SME3B002GTNACB00SSA0 SME3B004GTNACB00SSA0 SME3B008GTNDCB00SSA0
		1) C:0~70°C>> W:-40~85°C
	SLC	SDE1B016GTXDCBA0EAA0 SDE1B032GTXECBA0EAA0 SDE1B064GTXFCBA0EAA0 SDE1B128GTXFCBA0EAA0
	SLC	SDE1B016GTXDCBA0EAA0 SDE1B032GTXDCBA0EAA0 SDE1B064GTXDCBA0EAA0 SDE1B128GTXDCBA0EAA0
	SLC	SDE1B016GTXDCBA0EAA0 SDE1B032GTXDCBA0EAA0 SDE1B064GTXDCBA0EAA0 SDE1B128GTXDCBA0EAA0
	MLC	SDE1B032GTFDCB00SSA0 SDE1B064GTFDCB00SSA0 SDE1B128GTFDCB00SSA0 SDE1B256GTFDCB00SSA0
		1) C:0~70°C>> W:-40~85°C
	MLC	SDE1B032GTFDCB00SSA0 SDE1B064GTFDCB00SSA0 SDE1B128GTFDCB00SSA0 SDE1B256GTFDCB00SSA0
		1) C:0~70°C>> W:-40~85°C

	SLC	CFE9D128MTPACB00EAA0 CFE9D256MTPACB00EAA0 CFE9D512MTNACB00EAA0 CFE9D001GTNACB00EAA0 CFE9D002GTNACB00EAA0 CFE9D004GTNACB00EAA0 CFE9D008GTYBC00EAA0 CFE9D016GTYBC00EAA0 CFE9D032GTYBC00EAA0
		1) C:0~70°C>> W:-40~85°C
	SLC	SDE9D001GTNACB00EAA0 SDE9D002GTNACB00EAA0 SDE9D004GTNACB00EAA0 SDE9D008GTYBC00EAA0 SDE9D016GTYBC00EAA0 SDE9D032GTYBC00EAA0 SDE9D064GTYBC00EAA0
		1) C:0~70°C>> W:-40~85°C
	SLC	MMD4032GVJB00ABA0
		1) C:-25~85°C>> W:-40~85°C

	SLC	MMRD4512MVNAC00ABA0 MMRD4001GVNB00ABA0 MMRD4002GVNB00ABA0 MMRD4004GVYB00ABA0 MMRD4008GVYB00ABA0 MMRD4016GVYB00ABA0 MMRD4032GVYB00ABA0
		1) C:-25~85°C>> W:-40~85°C
	SLC	MURD4512MVNAC00ABA0 MURD4001GVNB00ABA0 MURD4002GVNB00ABA0 MURD4004GVNB00ABA0
		1) C:-25~85°C>> W:-40~85°C
	pSLC	MURD4001GVHAC00ABA0 MURD4002GVHAC00ABA0 MURD4004GVHAC00ABA0 MURD4016GVHAC00ABA0 MURD4032GVHAC00ABA0
		1) C:-25~85°C>> W:-40~85°C